

Tunable Thermal Switching via DNA-Based Nano Devices

Chih-Chun Chien,^{*,†} Kirill A. Velizhanin,^{†,‡} Yonatan Dubi,^{¶,§} and Michael Zwolak^{*,||}

Theoretical Division, Los Alamos National Laboratory, Los Alamos, NM 87545, CNLS, Los Alamos National Laboratory, Los Alamos, NM 87545, Landa Laboratories, 3 Pekeris St., Rehovot 76702, Israel, Department of Chemistry and the Ilse Katz Center for Nano-Science, Ben-Gurion University, Beer-sheva 84105, Israel, and Department of Physics, Oregon State University, Corvallis, OR 97331

E-mail: chihchun@lanl.gov; mpzwolak@physics.oregonstate.edu

Abstract

DNA has a well-defined structural transition – the denaturation of its double-stranded form into two single-strands – that strongly affects its thermal transport properties. We show that, according to a widely implemented model for DNA denaturation, one can engineer DNA “heatronic” devices that have a rapidly increasing thermal conductance over a narrow temperature range across the denaturation transition (~ 350 K). The origin of the switching behavior is the release of the base pairs from their confining potential as DNA denatures, which both softens the lattice and suppresses nonlinear effects, increasing the conductance. Most importantly, we demonstrate that DNA nanojunctions have a broad range of thermal tunability due to varying the sequence and length, and exploit the underlying nonlinear behavior. We discuss the role of disorder in the base sequence, as well as the re-

lation to genomic DNA. These results set the basis for developing thermal devices out of materials with nonlinear structural dynamics, as well as understanding the underlying mechanisms of DNA denaturation.

Introduction

Thermal transport in nanoscale materials and molecules has enormous potential in developing devices that manage heat in electronic and other systems.¹ For instance, thermal rectifiers^{2,3}, thermal transistors⁴, tunable thermal links⁵, and thermal memory^{6,7} have been experimentally demonstrated. One can envision that many more such devices will become feasible as methods are developed to engineer and control nonlinear effects in materials that transport heat.

Nature has provided us with a versatile and diverse nonlinear structure: DNA. Not only is the structural dynamics of DNA fundamentally interesting due to its relevance in biological processes, such as transcription⁸ and replication⁹, but DNA is also being used in constructing functional nanoscale devices, such as a template for electronic devices¹⁰ and molecular motors.¹¹ Thus, its ability to transport heat under different conditions is technologically important and may allow the “DNA template” to be exploited not just as a scaffold

^{*}To whom correspondence should be addressed

[†]Theoretical Division, Los Alamos National Laboratory, Los Alamos, NM 87545

[‡]CNLS, Los Alamos National Laboratory, Los Alamos, NM 87545

[¶]Landa Laboratories, 3 Pekeris St., Rehovot 76702, Israel

[§]Department of Chemistry and the Ilse Katz Center for Nano-Science, Ben-Gurion University, Beer-sheva 84105, Israel

^{||}Department of Physics, Oregon State University, Corvallis, OR 97331

fold but also as a functional device in itself. In addition to theoretical predictions¹², a recent experiment shows that incorporation of DNA into a device can indeed give rise to nonlinear behavior in the thermal current.¹³ The experimental setup examines a change in the thermal conductance from a combined duplex DNA and fluid conductor to a disordered single-stranded DNA layer, the latter being thermally insulating compared to the former. A complete theoretical reconstruction of the experimental results would thus need to delineate the role of DNA's intrinsic thermal conductance from the surrounding media, and examine a disordered layer of single-stranded DNA.

In this work, however, we envision instead a single molecule of duplex DNA bridging two thermal reservoirs in a vapor environment. We demonstrate that in this setup one can tune the thermal transport properties of DNA by taking advantage of its function as the carrier of the genetic code via its sequence of the four bases – Adenine (A), Guanine (G), Cytosine (C), Thymine (T). The sequence of bases determines both local structural properties that influence the thermal conductance and also where nonlinear effects give way to denaturation. Together with the length of DNA, these characteristics make DNA's thermal transport properties highly tunable. We demonstrate the “engineering principles” behind tuning thermal transport and set the foundations for developing novel thermal devices for applications in, e.g., nanoscale electronics.

Theoretical Analysis

Our starting point is the Peyrard-Bishop-Dauxois (PBD) model^{14–16}, which considers double-stranded DNA as a one-dimensional lattice of nonlinear oscillators. This model – the common model for the dynamics of DNA denaturation – captures the essential statistical features of DNA's structural transition and allows for the direct calculation of non-equilibrium thermal transport properties^{12 17}, see I. Within the PBD model, the DNA is described by the Hamiltonian

$$H = \sum_n \left[\frac{m_n \dot{y}_n^2}{2} + V_n(y_n) + W_n(y_n, y_{n-1}) \right], \quad (1)$$

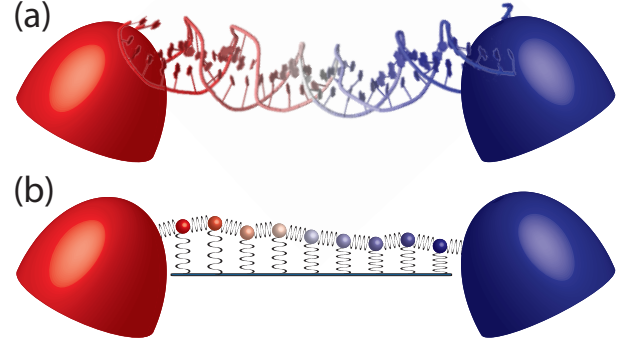


Figure 1: (a) Schematic of DNA between two thermal reservoirs. A hot reservoir (left, red) pumps heat into DNA, which can cause partial denaturation, and a cold reservoir (right, blue) absorbs heat from DNA. (b) Schematic of the PBD model for DNA dynamics. It represents DNA as a nonlinear lattice of fluctuating base pairs, i.e., the base to base distance in each base pair is confined in a non-linear (Morse) potential transverse to the backbone, neighboring bases couple only through the fluctuation of this coordinate. This does not include the helical nature of the ordered state. The strongly fluctuating denatured DNA is predicted to have higher thermal conductance according to the common model for DNA denaturation.

where each base pair (bp) of mass m_n is represented by stretching of its hydrogen bonds via the coordinate y_n . The onsite and nearest-neighbor interaction potentials, V_n and W_n , depend on the sequence of bases. The potentials take on the form $V_n(y_n) = D^n(e^{-a_n y_n} - 1)^2$ (known as the Morse potential), which describes hydrogen bonding and effective interactions due to the backbone/environment, and

$$W_n(y_n, y_{n-1}) = \frac{K^n}{2} (1 + \rho_n e^{-\beta_n(y_n + y_{n-1})})(y_n - y_{n-1})^2, \quad (2)$$

which describes the stacking interaction between neighboring base pairs. The scenario of interest is DNA in vapor similar to recent experiments, where it was shown that the PBD model still describes the transition well^{18 19}. For the analytic results, we consider a uniform stacking parameter, and then we address sequence dependent stacking using numerical results (see Ref. 20, 21, and the Supplemental Material for a detailed derivation and numerical parameters). We designate the se-

quence of DNA by the series of bases in one of the strands and its complementary strand is implicitly implied.

We will first focus on the thermal conductance ratio

$$R = \frac{\kappa_H}{\kappa_L},$$

where $\kappa_{L(H)}$ is the thermal conductance at low (high) temperatures. This quantity was introduced in Ref. 12 as a way to characterize a thermally induced structural transition. Here, we will examine its sequence dependence. When calculated using a small temperature change, e.g., around the denaturation temperature, it can play the role of an “on-off” ratio. We will see that adjusting the sequence and length of DNA can tune R while the sequence alone allows the transition temperature to be tuned within certain limits.

One of the main principles behind the nonlinear behavior predicted by the PBD model is captured in the low (L) and high (H) temperature limits of Eq. (??):

$$H_\mu = \sum_n \left[\frac{m_n \dot{y}_n^2}{2} + D_\mu^n y_n^2 + \frac{K_\mu^n}{2} (y_n - y_{n-1})^2 \right], \quad (3)$$

where $\mu = L, H$. We note that the PBD model is an effective model of DNA near the denaturation transition.²² However, these limiting forms that occur at much higher/lower temperatures give the appropriate physical description – within the PBD model – of DNA going from its double-stranded to single-stranded forms. With reservoirs attach on the end sites, the thermal conductance of an infinite strand in these limits has the form

$$\kappa \equiv \frac{J}{T_H - T_L} = \int_{\omega \in W} d\omega \mathfrak{T}(D_\mu^n, K_\mu^n, m, \gamma, \omega), \quad (4)$$

which can be calculated analytically (see Refs. 12,23,24 and the Supplemental Material). Here, J is the heat current, the integration is over the frequencies that correspond to propagating modes (W), γ characterizes the coupling strength to the reservoirs, and the transmission function \mathfrak{T} is determined by the structure of the lattice.

2(a) shows $\kappa_{L(H)}$ and R for an infinite strand with several different motifs, i.e., the basic unit cells of the DNA lattice. The high temperature conductance of all the sequences is identical due to the

uniform stacking interaction. The low temperature conductance, however, varies tremendously as the motif is changed and is universally much lower than its high temperature counterpart. This behavior is driven by two distinct physical mechanisms. First, going from the low temperature form to the high temperature form results in the release of the onsite confining potential upon denaturation. This leads to softening of the phonon modes and consequently to the increase of the thermal conductance, as described analytically in Ref. 12. Second, the introduction of different motifs introduces a mismatch between the different bases of the motif (due to their different binding potentials). This results in a narrowing and splitting of the phonon bands, as shown in 2(b), and a subsequent reduction in the low temperature thermal transport. In the extreme case of a semi-infinite poly(A) strand connected to a semi-infinite poly(G) strand the mismatch would be maximal. The phonon bands would have no overlap (see 2(b)) and the strand as the whole would have zero heat conduction within this model. Actual DNA, though, will have other contributions to heat conduction (e.g., the backbone), which will lead to a non-zero conductance.

A natural question to ask is what is the heat conductance of genomic or random sequences? Studying strands with periodic motifs helps understand the behavior of random sequences. An infinite random sequence – and likely genomic sequences – will look like a periodic strand with an extremely long motif. The allowed bandwidth of propagating modes will be narrowed by the large number of sites in the motif. Thus, we do not expect heat to be conducted efficiently and the low-temperature κ should be very small for random sequences (compared to a uniform sequence or an alternating sequence). Genomic DNA, of course, is always finite and not completely random. We expect, however, that the result will be similar to that of a random sequence. However, small regions of the genome can look very different from a random sequence, and nature may exploit sequence variation to optimize heat (signal) transport.

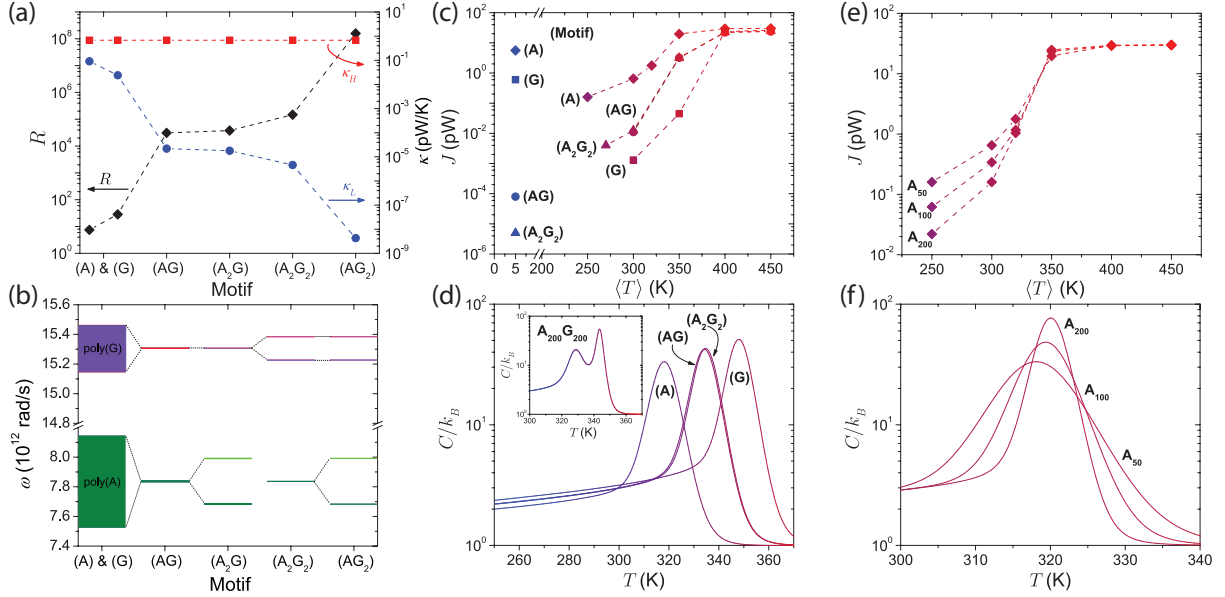


Figure 2: Engineering the thermal conductance of DNA. **(a)** The thermal conductance ratio and conductance for infinite strands with different periodic motifs at the high/low temperature limits of the PBD model. The low temperature conductance (blue circles), κ_L , drops precipitously as the motif of the sequence is enlarged while the high temperature conductance (red squares), κ_H , stays the same. The thermal conductance ratio, R , introduced in Ref. 12, is the ratio of the high to low temperature thermal conductance and characterizes how DNA's thermal conductance changes as it denatures. **(b)** Calculated phonon bands, from the lattice parameters used to fit the PBD model to experimental denaturation curves, for selected DNA sequences at low temperature. The left most bands are for a homogeneous sequence of G (upper, purple band) and a homogeneous sequence of A (lower, green band). As the motif is enlarged, the bands will become more narrow and also split. In other words, periodic sequences with increasing lengths of periodicity will decrease the bandwidth of the phonon modes, drastically reducing DNA's ability to conduct heat at low temperature. **(c, d)** Engineering the operation temperature of a DNA-based thermal device using the sequence dependence of the denaturation transition. **(c)** Heat current across select DNA sequences with $\Delta T=10$ K and with 90 bp length, where the first and the last 20 bp segments are connected to Langevin reservoirs. **(d)** Heat capacity normalized per number of base pairs for a 90 base-pair (bp) strand with periodic boundary conditions. The inset shows the heat capacity for an A₂₀₀G₂₀₀ repeat unit. The peak in the heat capacity marks the spot where DNA transitions into the denatured regime, and thus it sets the temperature where the increase in conductance ends. **(e, f)** Engineering the range of operation using the length of DNA. **(e)** Heat conductance of poly(A) of length 50, 100, and 200 bps (with an additional 20 bp segment connected to a reservoir at each end). **(f)** Heat capacity around the denaturation temperature for poly(A) of varying lengths.

Numerical Results and Discussions

The PBD model was developed to describe the properties of DNA around the denaturation transition. The analytic results above addressed high and low temperature limits (within the simplification of uniform stacking interactions). In order to understand the extent to which the values of R realized in 2(a) can be realized in a narrow temperature range around a transition, we perform numerical simulations of the full model including a sequence-dependent stacking interaction (parametrized in Ref. 21). The heat current is obtained by keeping the temperature difference between the heat baths constant ($T_H - T_L = 10$ K) and scanning the average temperature $\langle T \rangle = (T_H + T_L)/2$. We consider 90 base-pair (bp) long strands with 20 bps at each end connected to Langevin reservoirs. The damping of the individual sites by the reservoirs is 0.5 ps^{-1} . This is large enough to keep the very ends at the temperature of the reservoirs, while still allowing the sites to fluctuate at their natural frequency. The Supplemental Material has further details on the numerical simulations.

2(c) shows the heat current for several sequences. The analytical results above predicted that the heat conductance at temperatures higher than the melting temperature is insensitive to a particular sequence since the stacking interaction was assumed uniform. This is not the case in the numerical simulations, where the stacking potential assumes a more realistic sequence-dependent form. Accordingly, the heat current exhibits a dependence (although rather weak) on sequence in the temperature range 400 – 450 K. However, the heat conductance of DNA increases drastically when the temperature crosses the denaturation point. That this is indeed the denaturation transition where the conduction of DNA strand changes rapidly (versus temperature) can be seen by the correspondence between these curves and the peaks in the heat capacity shown in 2(d). Around the transition, poly(AG) and poly(A₂G₂) have about the same conductance and heat capacity, implying that the denaturation bubbles – where the two strands locally come apart – are much

longer than the motif and, thus, only the average sequence matters. Thus, *the sequence will change the denaturation temperature and tune the “operating temperature” of the device.* The GC base pair has a higher dissociation energy than AT, and thus its incorporation into a strand increases the transition temperature.

Furthermore, while the sequence can change R measured by the high/low temperature limits and the “operating” temperature, the on-off ratio around the “operating” temperature does not drastically change. However, tuning the length of the DNA nano-junction allows one to tune this important device characteristic. 2(e) shows the heat conductance of poly(A) strands of various lengths. Below the transition, the strand is anharmonic and is expected to demonstrate finite well-defined *conductivity*, i.e., the conductance is expected to be inversely proportional to the length of the strand so long as this length is longer than the typical bubble size. As seen in 2(e), near (and above) the transition, the conductance weakly depends on the length, signifying that the harmonic, high temperature Hamiltonian is being approached. This is further supported by 2(f), where above the transition point the heat capacity is seen to rapidly approach $C/k_B = 1$ – the harmonic limit.

At temperatures further below the transition, the conductance drops inversely with length of the DNA within the error of the simulations²⁵. This observation is in agreement with the heat capacity which shows the transition narrowing for longer strands of DNA. This is simply an indication that as the bubble length becomes comparable to the strand length, denaturation has effectively occurred and this smears out the transition temperature range. We conjecture that using sequence effects (e.g., the suppression of the low temperature conductance shown in 2(a)) together with length will allow for even more drastic on-off jumps in the conductance. However, a more detailed study of DNA, including backbone effects, will be required to investigate this issue.

Conclusion

To summarize, we have examined the thermal transport properties of DNA as described by the

PBD model and predicted that DNA nano-devices act as a *thermal switch* – where the thermal conductance rises many orders of magnitude as the temperature of the DNA strand is driven across the denaturation transition. The operating principle behind this behavior is the release of the base pairs from their confining potential, which both softens the lattice and suppresses nonlinear effects.²⁶ Using analytic calculations and numerical simulations with sequence-specific parameters, we have shown that the operating temperature of the thermal switch can be tuned by choosing different DNA motifs and that the "on/off" ratio can be tuned by the DNA length.

Further possibilities for engineering thermal transport may be offered by molecular or chemical modification of the nucleotides, using much longer sequences (e.g., see the inset of 2(d), showing that a two step jump in conductance may be possible), and exploiting extrinsic changes in heat conduction (e.g., due to a structural change modifying the surrounding environment in addition to changing intrinsic properties, as in a recent experiment¹³). This work sets the foundation to developing thermal switches out of materials and molecules with nonlinear structural dynamics. In addition, it will allow one to test underlying mechanisms for structural transitions¹² and, in particular, the dynamical behavior captured within the PBD model.^{12,27,28} We speculate that biological systems may take advantage of such nonlinear behavior in engineering their own control of heat flow and signaling.

Acknowledgement This work was performed under the NNSA of the U.S. DOE at LANL under LDRD and Contract No. DE-AC52-06NA25396, and, in part, by ONR and NAS/LPS. K.A.V. also acknowledges support provided by CNLS.

References

1. Dubi, Y.; Di Ventra, M. Colloquium: Heat Flow and Thermoelectricity in Atomic and Molecular Junctions. *Rev. Mod. Phys.* **2011**, *83*, 131–155.
2. Chang, C. W.; Okawa, D.; Majumdar, A.; Zettl, A. Solid-State Thermal Rectifier. *Science* **2006**, *314*, 1121–1124.
3. Schmotz, M.; Maier, J.; Scheer, E.; Leiderer, P. A Thermal Diode Using Phonon Rectification. *New Journal of Physics* **2011**, *13*, 113027 (1–8).
4. Saira, O.-P.; Meschke, M.; Giazotto, F.; Savin, A. M.; Möttönen, M.; Pekola, J. P. Heat Transistor: Demonstration of Gate-Controlled Electronic Refrigeration. *Phys. Rev. Lett.* **2007**, *99*, 027203 (1–4).
5. Chang, C. W.; Okawa, D.; Garcia, H.; Yuzvinsky, T. D.; Majumdar, A.; Zettl, A. Tunable Thermal Links. *Appl. Phys. Lett.* **2007**, *90*, 193114 (1–3).
6. Wang, L.; Li, B. Thermal Memory: A Storage of Phononic Information. *Phys. Rev. Lett.* **2008**, *101*, 267203 (1–4).
7. Xie, R.; Bui, C. T.; Varghese, B.; Zhang, Q.; Sow, C. H.; Li, B.; Thong, J. T. L. An Electrically Tuned Solid-State Thermal Memory Based on Metal-Insulator Transition of Single-Crystalline VO₂ Nanobeams. *Adv. Funct. Mater.* **2011**, *21*, 1602–1607.
8. Chen, J.; Darst, S. A.; Thirumalai, D. Promoter Melting Triggered by Bacterial RNA Polymerase Occurs in Three Steps. *Proc. Natl. Acad. Sci. U. S. A.* **2010**, *107*, 12523–12528.
9. Alberts, B.; Johnson, A.; Lewis, J.; Raff, M.; Roberts, K.; Walter, P. *Molecular Biology of the Cell*, 4th edition; Garland Science: New York, 2002.
10. Di Ventra, M.; Zwolak, M. In *Encyclopedia of Nanoscience and Nanotechnology*; Singh-Nalwa, H., Ed.; American Scientific Publishers, 2004; Vol. 2; p 475.
11. Omabegho, T.; Sha, R.; Seeman, N. C. A Bipedal DNA Brownian Motor with Coordinated Legs. *Science* **2009**, *324*, 67–71.
12. Velizhanin, K. A.; Chien, C.-C.; Dubi, Y.; Zwolak, M. Driving Denaturation: Nanoscale Thermal Transport as a Probe of DNA Melting. *Phys. Rev. E* **2011**, *83*, 050906 (1–4).

13. van Grinsven, B.; Vanden Bon, N.; Strauven, H.; Grieten, L.; Murib, M.; Jiménez Monroy, K. L.; Janssens, S. D.; Haenen, K.; Schöning, M. J.; Vermeeren, V. et al. Heat-Transfer Resistance at Solid-Liquid Interfaces: A Tool for the Detection of Single-Nucleotide Polymorphisms in DNA. *ACS Nano* **2012**, *6*, 2712–2721.
14. Peyrard, M.; Bishop, A. R. Statistical Mechanics of a Nonlinear Model for DNA Denaturation. *Phys. Rev. Lett.* **1989**, *62*, 2755–2758.
15. Dauxois, T.; Peyrard, M.; Bishop, A. R. Entropy-Driven DNA Denaturation. *Phys. Rev. E* **1993**, *47*, R44–R47.
16. Dauxois, T.; Peyrard, M.; Bishop, A. R. Dynamics and Thermodynamics of a Nonlinear Model for DNA Denaturation. *Phys. Rev. E* **1993**, *47*, 684–695.
17. We note that other theoretical work has examined thermal transport in models of DNA.^{29–31} However, these have not examined the strong nonlinear effects during denaturation, which is our focus here and in Ref. 12.
18. Wildes, A.; Theodorakopoulos, N.; Valle-Orero, J.; Cuesta-Lopez, S.; Garden, J.-L.; Peyrard, M. Thermal Denaturation of DNA Studied with Neutron Scattering. *Phys. Rev. Lett.* **2011**, *106*, 048101 (1–4).
19. The PBD model, or a PBD-like model, may be applicable even in vacuum, as it was shown that the DNA duplex can retain some of its structural properties under extreme conditions³².
20. Campa, A.; Giansanti, A. Experimental Tests of the Peyrard-Bishop Model Applied to the Melting of Very Short DNA Chains. *Phys. Rev. E* **1998**, *58*, 3585–3588.
21. Alexandrov, B. S.; Gelev, V.; Monisova, Y.; Alexandrov, L. B.; Bishop, A. R.; Rasmussen, K. Ø.; Usheva, A. A Nonlinear Dynamic Model of DNA with a Sequence-Dependent Stacking Term. *Nucleic Acids Res.* **2009**, *37*, 2405–2410.
22. The PBD model only includes oscillations that describe base pair opening fluctuations. It does not include fluctuations of the atomic constituents of the backbone. This, of course, will change the thermal conductance. One would expect that the low temperature thermal conductance of random sequences would be mostly due to backbone contributions, and thus the low temperature conductance should not fall to zero but level off at some finite value. However, since the thermal conductance is dependent on frequency, these higher frequency, localized modes should contribute less to the conductance for moderately sized homogeneous motifs. This will be the subject of a future investigation.
23. Casher, A.; Lebowitz, J. L. Heat Flow in Regular and Disordered Harmonic Chains. *J. Math. Phys.* **1971**, *12*, 1701–1711.
24. Dhar, A. Heat Conduction in the Disordered Harmonic Chain Revisited. *Phys. Rev. Lett.* **2001**, *86*, 5882 (1–4).
25. We note that, right at the transition, the shorter DNA actually has lower conductance. This is likely due to the effect of the “clamped” ends, which make anharmonic effects more important for the shorter strands due to keeping the bases at the ends in the bound state..
26. The latter of these is the most important for observing the increase before the transition: We have extensively examined the model of Joyeux and Buyukdagli³³. There are important differences between this model and the PBD model¹², but the increase in conductance before the transition is not one of them. They both predict a large increase as bubbles become larger and larger, and this strong, temperature dependent source of nonlinearity is released.
27. Peyrard, M. Nonlinear Dynamics and Statistical Physics of DNA. *Nonlinearity* **2004**, *17*, R1–R40.
28. Peyrard, M.; Cuesta-López, S.; James, G. Modelling DNA at the Mesoscale: A Chal-

lenge for Nonlinear Science? *Nonlinearity* **2008**, *21*, T91–T100.

29. Terraneo, M.; Peyrard, M.; Casati, G. Controlling the Energy Flow in Nonlinear Lattices: A Model for a Thermal Rectifier. *Phys. Rev. Lett.* **2002**, *88*, 094302 (1–4).
30. Peyrard, M. The Design of a Thermal Rectifier. *EPL (Europhysics Letters)* **2006**, *76*, 49–55.
31. Savin, A. V.; Mazo, M. A.; Kikot, I. P.; Manevitch, L. I.; Onufriev, A. V. Heat Conductivity of the DNA Double Helix. *Phys. Rev. B* **2011**, *83*, 245406 (1–15).
32. Rueda, M.; Kalko, S. G.; Luque, F. J.; Orozco, M. The Structure and Dynamics of DNA in the Gas Phase. *J. Am. Chem. Soc.* **2003**, *125*, 8007–8014.
33. Joyeux, M.; Buyukdagli, S. Dynamical model based on finite stacking enthalpies for homogeneous and inhomogeneous DNA thermal denaturation. *Phys. Rev. E* **2005**, *72*, 051902.

Supplemental Material for “Tunable Thermal Switching via DNA-Based Nano Devices”

Chih-Chun Chien,^{1,*} Kirill A. Velizhanin,^{1,2} Yonatan Dubi,^{3,4} and Michael Zwolak^{5,†}

¹*Theoretical Division, Los Alamos National Laboratory, Los Alamos, NM 87545*

²*CNLS, Los Alamos National Laboratory, Los Alamos, NM 87545*

³*Landa Laboratories, 3 Pekeris St., Rehovot 76702, Israel*

⁴*Department of Chemistry and the Ilse Katz Center for Nano-Science, Ben-Gurion University, Beer-sheva 84105, Israel*

⁵*Department of Physics, Oregon State University, Corvallis, OR 97331*

(Dated: July 23, 2012)

I. BASIC MODEL AND PARAMETERS

In the main text we discuss the thermal transport properties of a DNA nano-junction. We designate the sequence of DNA by the series of bases in one of the strands and its complementary strand is implicitly implied. Furthermore, a DNA sequence with a periodic motif is denoted by, e.g., poly(AG), which is the alternating sequence AGAGAG...

We describe the DNA in the framework of the PBD model [1–3] widely used to describe the dynamics of DNA denaturation. Essentially, the DNA is represented as a set of balls and springs with the balls representing the base-pair stretching and the springs encoding the complex interactions of bases within pairs (H-bonding) and between pairs (stacking). The PBD Hamiltonian is

$$H = \sum_n \left[\frac{m\dot{y}_n^2}{2} + V_n(y_n) + W_n(y_n, y_{n-1}) \right]. \quad (1)$$

y_n is the stretching of the base pair hydrogen bonds, and m_n are the masses of the base pairs, which are assumed uniform throughout the strand with $m_n = m = 300$ a.m.u. [4, 5]. The functions $V(y_n)$ and $W(y_n, y_{n-1})$ describe the effective (intra-pair) potential felt by the hydrogen bond and the effective inter-pair stacking interaction, respectively. These potentials take the form

$$V_n(y_n) = D^n (e^{-a_n y_n} - 1)^2$$

$$W_n(y_n, y_{n-1}) = \frac{K^n}{2} (1 + \rho_n e^{-\beta_n(y_n + y_{n-1})})(y_n - y_{n-1})^2. \quad (2)$$

Recently developed parameters [4, 5] of the Morse potential for complementary base pairs are $D^{A-T} = 0.05$ eV, $a_{A-T} = 4.2 \text{ \AA}^{-1}$ for the $A-T$ base pair, and $D^{G-C} = 0.075$ eV, $a_{G-C} = 6.9 \text{ \AA}^{-1}$ for the $G-C$ base pair. The parameters of the stacking interaction between successive base pairs depends on both the pairs and their orientation. However, we first consider the uniform “average” stacking potential with parameters $K^n = K = 0.025 \text{ eV/\AA}^{-2}$, $\rho_n = \rho = 2$, and $\beta = 0.35 \text{ \AA}^{-1}$ [5]. The effect of the sequence-dependent stacking interaction is addressed in the numerical simulations using the Langevin equation.

II. ANALYTIC DERIVATION OF THE THERMAL CONDUCTANCE

The thermal conductance of a classical harmonic lattice can be found analytically. Our starting point is to consider the limiting cases of the single-coordinate Hamiltonian (Eq. (1) in the main text) for a lattice of length N . The details of the high and low-temperature expansions were presented in Ref. [6]. The low- (L) and high- (H) temperature limits can be approximated by a harmonic Hamiltonian of the form

$$H_\mu = \sum_n \left[\frac{m\dot{y}_n^2}{2} + D_\mu y_n^2 + \frac{K_\mu}{2} (y_n - y_{n-1})^2 \right], \quad (3)$$

where $\mu = L, H$, and the corresponding coefficients $K_H = K$, $D_H = 0$ and $K_L = K(1 + \rho)$, $D_L = Da^2$.

Once a harmonic Hamiltonian is obtained, one can follow the procedure of Refs. [7, 8]. To simplify the analysis, the lattice is coupled to two heat reservoirs at the first and last sites, which gives the equations of motion

$$m\ddot{y}_n = -2(D_\mu^n + K_\mu)y_n + K_\mu(y_{n-1} + y_{n+1}) + (\delta_{n,1} + \delta_{n,N_t}) \left[\int_{-\infty}^t dt' A(t-t')y_n(t') + \eta_n(t) \right]. \quad (4)$$

We choose the spectrum of the dissipation to be ohmic, $A(\omega) = -i\gamma\omega$, with coupling γ , and the noise to be a white noise, $\langle \eta_{L/H}(\omega)\eta_{L/H}(\omega') \rangle = 4\pi T_{L/H}\gamma\delta(\omega + \omega')$, with $T_{L/H}$ the low and high reservoir temperatures. We consider a periodic lattice of length $N_t = N \times N_s$, where N_s is the length of the motif. This form for the reservoirs will satisfy the fluctuation-dissipation theorem. The resulting equations of motion are

$$m\ddot{y}_n = -2(D_\mu^n + K_\mu)y_n + K_\mu(y_{n-1} + y_{n+1}) + (\delta_{n,1} + \delta_{n,N_t}) [-\gamma\dot{y}_n(t) + \eta_n(t)]. \quad (5)$$

The solution for the coordinates has the form

$$y_n(t) = (1/2\pi) \int_{-\infty}^{\infty} d\omega \hat{Y}_{nm}^{-1}(\omega) \hat{\eta}_m(\omega) e^{i\omega t}, \quad (6)$$

where $\hat{\eta}$ is a vector of length N_t with the first and last components being $\eta_{L/H}(\omega)$ and the rest being zero. It

represents the coupling of the reservoirs to the ends of the lattice. The $N_t \times N_t$ matrix $\hat{Y} = \hat{\phi} - \omega^2 \hat{M} - \hat{A}$ encodes the solution. Here $\hat{\phi}_{nm} = 2(D_\mu^n + K_\mu)\delta_{n,m} - K_\mu\delta_{n,m+1} - K_\mu\delta_{n,m-1}$, $\hat{M}_{ij} = m\delta_{i,j}$, and $\hat{A}_{11} = \hat{A}_{N_t N_t} = A(\omega)$ and $\hat{A}_{nm} = 0$ otherwise.

The heat current flowing into the lattice is $J = \langle [\int_{-\infty}^t dt' A(t-t') y_1(t')] \dot{y}_1(t) \rangle$, where the average is over the noise. Setting $\gamma = \lambda m$, the heat current becomes

$$J_\mu = \frac{\Delta T \lambda^2 m^2}{\pi} \int_{-\infty}^{\infty} d\omega \omega^2 \{ (\mathcal{D}_{1,N_t} - \lambda^2 \omega^2 m^2 \mathcal{D}_{2,N_t-1})^2 + \lambda^2 \omega^2 m^2 (\mathcal{D}_{1,N_t-1} + \mathcal{D}_{2,N_t})^2 \}^{-1} |C_{1,N_t}|^2, \quad (7)$$

where $\Delta T = T_H - T_R$ is the temperature difference of the reservoirs, C_{1,N_t} is the cofactor of $\hat{Y}_{1,N}$, and $\mathcal{D}_{n,m}$ is the determinant of the submatrix of $(\hat{\phi} - \omega^2 \hat{M})$ from the n -th row (column) to the m -th row (column). It follows that $|C_{1,N_t}|^2 = K_\mu^{2N_t-2}$ and $\mathcal{D}_{n,m} = K_\mu^{n-m+1} \mathcal{D}_{n,m}^0$.

The elements $\begin{pmatrix} \mathcal{D}_{1,2N_t}^0 & -\mathcal{D}_{1,2N_t-1}^0 \\ \mathcal{D}_{2,2N_t}^0 & -\mathcal{D}_{2,2N_t-1}^0 \end{pmatrix} = [\mathcal{T}_s]^N$, where $\mathcal{T}_s = \mathcal{T}_1 \mathcal{T}_2 \cdots \mathcal{T}_{N_s}$ is the composite transfer matrix of one segment with length N_s . Since each transfer matrix \mathcal{T}_i is unimodular, for an infinite lattice the allowed propagating modes correspond to \mathcal{T}_s with eigenvalues $e^{\pm i q}$. We notice that for those propagating modes,

$$\mathcal{D}_{1,N_s}^0 - \mathcal{D}_{2,N_s-1}^0 = 2 \cos(q). \quad (8)$$

This equation determines $\omega(q)$. In general, for a basis with N_s elements, there are N_s bands that satisfy Eq. (8) though the bandwidths can be substantially reduced as N_s increases. Moreover, $[\mathcal{T}_s]^N = [\cos(Nq)] \mathbf{1} + [\sin(Nq)/\sin(q)] [\mathcal{T}_s - (\cos(q)) \mathbf{1}]$, where $\mathbf{1}$ is the 2×2 identity matrix. Then we rewrite the denominator of Eq. (7) as $|z_A|^2$, where $z_A = (1 + \lambda^2 \omega^2 m^2 / K_\mu^2) \cos(Nq) + (\sin(Nq)/\sin(q))(z_c - (1 + \lambda^2 \omega^2 m^2 / K_\mu^2) \cos(q))$ and $z_c = (\mathcal{D}_{1,N_s}^0 - \lambda^2 \omega^2 m^2 \mathcal{D}_{2,N_s-1}^0 / K_\mu^2) - i \lambda \omega (m / K_\mu) (\mathcal{D}_{1,N_s-1}^0 + \mathcal{D}_{2,N_s}^0)$. Eq. (8) determines $\omega(q)$ so the integration of Eq. (7) can be considered as an integration over q for those propagating modes. As $N \rightarrow \infty$, one uses the formula $\int_0^{2\pi} dq F(q, Nq) \rightarrow \frac{1}{2\pi} \int_0^{2\pi} dq \int_0^{2\pi} dx F(q, x)$ by treating $x = Nq$ as an independent variable in the $N \rightarrow \infty$ limit. After integrating over x and q , one obtains the thermal current.

For a uniform lattice, $N_s = 1$ and $D_\mu^n = D_\mu$ so

$$\mathcal{T}_s = \mathcal{T}_1 = \begin{pmatrix} 2(1 + D_\mu/K_\mu) - (m/K_\mu)\omega^2 & -1 \\ 1 & 0 \end{pmatrix}. \quad (9)$$

Eq. (8) gives $2 \cos(q) = 2(1 + D_\mu/K_\mu) - (m/K_\mu)\omega^2$. After changing variables from ω to q that satisfy this constraint, the final expression (for an infinite lattice ($N \rightarrow \infty$)) is

$$\frac{J_\mu}{\Delta T} = \frac{\gamma}{2\pi m} \int_0^{2\pi} dq \frac{\sin^2(q)}{1 + \frac{2\gamma^2}{mK_\mu} \left[1 + \frac{D_\mu}{K_\mu} - \cos(q) \right]}. \quad (10)$$

This gives for the low and high temperature thermal conductance, $\kappa_\mu = J_\mu / \Delta T$,

$$\kappa_\mu = \frac{k_B m K_\mu^2}{4\gamma^3} \left[1 + \frac{2\gamma^2}{mK_\mu} + \frac{2\gamma^2 D_\mu}{mK_\mu^2} - \mathcal{B}_\mu \right], \quad (11)$$

with

$$\mathcal{B}_\mu = \sqrt{1 + \frac{4\gamma^2}{mK_\mu} + \frac{4\gamma^2 D_\mu}{mK_\mu^2} + \frac{8\gamma^4 D_\mu}{m^2 K_\mu^3} + \frac{4\gamma^4 D_\mu^2}{m^2 K_\mu^4}}. \quad (12)$$

With these expressions one can explicitly find the thermal conductance ratio R . We have verified that for reservoirs contacted to a single site on each end, the thermal conductance from our numerical simulations agree with our analytic formula to within 10 – 15%. The error may be attributed to finite size effects in the numerical simulations.

We can take various limiting forms of these equations. If we define the prefactor as $\tilde{\kappa}_\mu$ and a dimensionless reservoir coupling as

$$\gamma_\mu = \frac{\gamma}{\sqrt{mK_\mu}}, \quad (13)$$

the expressions for the conductance become

$$\kappa_\mu = \tilde{\kappa}_\mu \left[1 + 2\gamma_\mu^2 + 2\gamma_\mu^2 \frac{D_\mu}{K_\mu} - \mathcal{B}_\mu \right], \quad (14)$$

with

$$\mathcal{B}_\mu = \sqrt{1 + 4\gamma_\mu^2 + 4\gamma_\mu^2 \frac{D_\mu}{K_\mu} + 8\gamma_\mu^4 \frac{D_\mu}{K_\mu} + 4\gamma_\mu^4 \left(\frac{D_\mu}{K_\mu} \right)^2}. \quad (15)$$

The appropriate limiting forms for our case are the following. When the high temperature harmonic limit has no onsite potential, then the heat conductance becomes

$$\kappa_H = \tilde{\kappa}_H \left[1 + 2\gamma_H^2 - \sqrt{1 + 4\gamma_H^2} \right]. \quad (16)$$

For the low temperature limit that has a much greater onsite term than the nearest neighbor coupling, i.e., $K_L/D_L \ll 1$, the heat conductance becomes

$$\kappa_L \approx \frac{\tilde{\kappa}_L \gamma_L^2 K_L}{D_L}, \quad (17)$$

which also assumes that the dimensionless coupling to the reservoirs is $\gamma_L \geq 1$. For strong coupling to the reservoirs, the ratio becomes

$$R \approx \frac{2K_H D_L}{K_L^2}. \quad (18)$$

This is the analytic expression that demonstrates that softening of a harmonic lattice increases the thermal conductance ratio ($D_L \propto \omega_L^2$). The strong coupling limit gives the extreme value of R .

Now we show that the characteristic frequency in the PBD model is lowered as T crosses T_c from below. For the low temperature Hamiltonian, the corresponding equation of motion is

$$m\ddot{y}_n = -\{2Da^2y_n + K(1+\rho)[(y_n - y_{n-1}) + (y_n - y_{n+1})]\}. \quad (19)$$

From the ansatz $y_n = y_n^0 e^{i\omega t - ikn}$, one obtains the phonon spectrum as

$$m\omega^2 = 2Da^2 + 2K(1+\rho)[1 - \cos(k)]. \quad (20)$$

Thus, the frequency band of phonons is $\sqrt{2Da^2/m} \leq \omega \leq \sqrt{[2Da^2 + 4K(1+\rho)]/m}$. For the high temperature Hamiltonian, the equation of motion is

$$m\ddot{y}_n = -K[(y_n - y_{n-1}) + (y_n - y_{n+1})] \quad (21)$$

and the phonon spectrum is

$$m\omega^2 = 2K[1 - \cos(k)]. \quad (22)$$

The frequency band of phonons is $0 \leq \omega \leq \sqrt{4K/m}$. The two limiting Hamiltonians are both harmonic and the characteristic frequency is indeed lowered, and similar considerations apply for other models. In the low temperature limit, the onsite potential stiffens the DNA compared to the high temperature limit, which results in the raising of the phonon spectrum of the low temperature limit compared to the high temperature. In the latter, as well, the nearest neighbor coupling drops from $K(1+\rho)$ to K shrinking the bandwidth. This trade-off is responsible for the change in thermal conductance across the transition. If the drop in nearest neighbor coupling is small, then the softening will dominate, and the heat conductance will increase because these softened modes can conduct heat more effectively.

Next we consider a lattice with periodic segments. For a periodic lattice with alternating (AG) pairs, $N_s = 2$ so there are two onsite parameters $D_{\mu}^{1,2}$ and $\mathcal{T}_s = \mathcal{T}_1\mathcal{T}_2 = \begin{pmatrix} \mathcal{D}_{1,2}^0 & -\mathcal{D}_{2,2}^0 \\ \mathcal{D}_{1,1}^0 & -\mathcal{D}_{2,1}^0 \end{pmatrix} = \begin{pmatrix} [x_1] & -1 \\ 1 & 0 \end{pmatrix} \begin{pmatrix} [x_2] & -1 \\ 1 & 0 \end{pmatrix}$, where $[x_1] \equiv 2(1 + \frac{D_{\mu}^1}{K_{\mu}}) - \frac{m}{K_{\mu}}\omega^2$ and $[x_2] \equiv 2(1 + \frac{D_{\mu}^2}{K_{\mu}}) - \frac{m}{K_{\mu}}\omega^2$. From Eq. (8) and $|\cos(q)| \leq 1$ one can find two bands which satisfy the condition:

$$u_{b1} \leq \omega^2 \leq u_{b2} \text{ and } u_{t1} \leq \omega^2 \leq u_{t2}. \quad (23)$$

Here $u_{b1} = (K_{\mu}/m)[2 + (D_{\mu}^1 + D_{\mu}^2)/K_{\mu} - \sqrt{4 + (D_{\mu}^1 - D_{\mu}^2)^2/K_{\mu}^2}]$, $u_{b2} = 2(K_{\mu}/m)(1 + D_{\mu}^1/K_{\mu})$, $u_{t1} = 2(K_{\mu}/m)(1 + D_{\mu}^2/K_{\mu})$, and $u_{t2} = (K_{\mu}/m)[2 + (D_{\mu}^1 + D_{\mu}^2)/K_{\mu} + \sqrt{4 + (D_{\mu}^1 - D_{\mu}^2)^2/K_{\mu}^2}]$.

One can show that the current is

$$\begin{aligned} \frac{J}{\Delta T} &= \frac{\lambda}{\pi} \frac{m^2}{K_{\mu}^2} \int_{\omega \in W} d\omega |\omega \sin(q)| [(1 + \lambda^2 \omega^2 m^2 / K_{\mu}^2) \times \\ &\quad (m/K_{\mu}) |\mathcal{D}_{1,1}^0 + \mathcal{D}_{2,2}^0|]^{-1} \\ &= \frac{\lambda m}{2\pi K_{\mu}} \left(\int_{u_{b1}}^{u_{b2}} + \int_{u_{t1}}^{u_{t2}} \right) du \sqrt{1 - \cos^2(q)} [(1 + \\ &\quad \lambda^2 m^2 u / K_{\mu}^2) (4 + 2D_{\mu}^1/K_{\mu} + 2D_{\mu}^2/K_{\mu} - \\ &\quad 2mu/K_{\mu})]^{-1}. \end{aligned} \quad (24)$$

Here we have used $u = \omega^2$ and $\cos(q(u)) = (1/2)[(2(1 + D_{\mu}^1/K_{\mu}) - mu/K_{\mu})[2(1 + D_{\mu}^2/K_{\mu}) - mu/K_{\mu}] - 1]$ from Eq. (8).

The heat currents for more complicated bases can be derived in a similar way. For example, the heat current for a poly(A₂G) strand is given by

$$\frac{J}{\Delta T} = \frac{\lambda m}{2\pi K_{\mu}} \int_{\omega \in W} du \sqrt{1 - \cos^2(q)} [(1 + \lambda^2 m^2 u / K_{\mu}^2) ([x_1][x_2] + [x_1]^2 - 2)]^{-1} \quad (25)$$

Here the three conduction bands are determined by $2\cos(q) = \mathcal{D}_{1,3}^0 - \mathcal{D}_{2,2}^0 = [x_1]^2[x_2] - 2[x_1] - [x_2]$. The heat current for a poly(A₂G₂) strand is

$$\frac{J}{\Delta T} = \frac{\lambda m}{2\pi K_{\mu}} \int_{\omega \in W} du \sqrt{1 - \cos^2(q)} [(1 + \lambda^2 m^2 u / K_{\mu}^2) \times ([x_1]^2[x_2] + [x_1][x_2]^2 - 2[x_1] - 2[x_2])]^{-1} \quad (26)$$

The four conduction bands are determined by $2\cos(q) = \mathcal{D}_{1,4}^0 - \mathcal{D}_{2,3}^0$, where $\mathcal{D}_{1,4}^0 = [x_1]^2[x_2]^2 - [x_1][x_2] - [x_1]^2 - [x_2]^2 + 1$, $\mathcal{D}_{2,3}^0 = [x_1][x_2] - 1$, $\mathcal{D}_{1,3}^0 = [x_1][x_2]^2 - [x_1] - [x_2]$, and $\mathcal{D}_{2,4}^0 = [x_1]^2[x_2] - [x_1] - [x_2]$.

For parameters relevant to real DNA, we have evaluated the thermal conductance (in the harmonic limit) of poly(A), poly(G) homogeneous lattices as well as poly(AG), poly(A₂G), poly(AG₂) and poly(A₂G₂). They qualitatively agree with our numerical simulations.

III. SIMULATION DETAILS

A. Transfer matrix

The transfer matrix formalism is based on the possibility to evaluate the partition function for a classical non-linear lattice using the matrix algebra [9]. Specifically, the total classical partition function for the PBD model is given by

$$\mathcal{Z} = \mathcal{Z}_T \mathcal{Z}_U, \quad (27)$$

where $\mathcal{Z}_T = (2\pi mk_B T)^{N/2}$ is the “kinetic” partition function and the “potential” partition function reads as

$$\mathcal{Z}_U = \int \prod_{n=1}^N dy_n e^{-[V_n(y_n) + W_n(y_n, y_{n-1})]/k_B T}. \quad (28)$$

The continuous integration can be represented through summation on the grid yielding for periodic boundary conditions (i.e., $y_0 \equiv y_N$)

$$\mathcal{Z}_U = \text{Tr} \left[\prod_{n=1}^N \hat{M}_n \right], \quad (29)$$

where matrix \hat{M}_n is defined through its matrix elements as

$$[\hat{M}_n]_{ij} = \Delta x e^{\left[\frac{1}{2} V_n(x_i) + W_n(x_i, x_j) + \frac{1}{2} V_{n-1}(x_j) \right] / k_B T}, \quad (30)$$

where x_i is the coordinate on the grid with the grid step Δx , i.e., $x_i = x_0 + i\Delta x$. The parameters of the grid used in our calculations are $x_{\min} = -1.5 \text{ \AA}$, $x_{\max} = 50 \text{ \AA}$ with $\Delta x = 0.05 \text{ \AA}$.

In the case of a homogeneous lattice, i.e., if $V_n(y_n) \equiv V(y_n)$ and $W_n(y_n, y_{n-1}) \equiv W(y_n, y_{n-1})$, all the matrices \hat{M}_n are identical and symmetric, which results in the possibility to evaluate the trace in Eq. (29) as $\mathcal{Z}_U = \sum_i \lambda_i^N$, where λ_i are the eigenvalues of symmetric matrix \hat{M}_n . Naturally, if the lattice becomes very long, only the largest eigenvalue, λ_{\max} of the transfer matrix contributes to the partition function yielding $\mathcal{Z}_U = \lambda_{\max}^N$.

The natural generalization of this procedure to the case of DNA strand made of repeating motif is as follows. First, matrices corresponding to a single repeating unit (r) are multiplied yielding $\hat{M}_r = \prod_{n \in r} \hat{M}_n$. The potential partition function is given by $\text{Tr}[\hat{M}_r^{N_r}]$, where N_r is the number of repeat units in the strand with periodic boundary conditions. Therefore, the potential partition function becomes $\mathcal{Z}_U = \sum_i v_i^{N_r}$, where v_i are the eigenvalues of \hat{M}_r . We note here, that even though matrix \hat{M}_r might not be symmetric, the eigenvalue problem for such a matrix is still well defined and eigenvalues is all what is needed to evaluate the “potential” partition function above. Specifically, it can be shown that the Schur decomposition, which yields eigenvalues, is always possible for any square matrix. This decomposition does not guarantee the completeness of the eigenvector-based basis, but *only* knowledge of eigenvalues is required for the evaluation of the potential partition function for the lattice with periodic boundary conditions.

Once the partition functions are found, the heat capacity of the DNA strand, normalized per number of sites, can be evaluated as

$$C = -\frac{T}{N} \frac{\partial^2 F}{\partial T^2}, \quad (31)$$

where $F = -k_B T \ln(\mathcal{Z}_T \mathcal{Z}_U)$ is the free energy of the DNA strand.

B. Langevin dynamics

To study the dynamics of the DNA out of equilibrium we solve numerically the Langevin equation, which de-

	$K(\text{eV}/\text{\AA}^2)$
AA	0.023
GG	0.019
AG	0.0232
GA	0.0185

Table I. Harmonic parameter of the sequence-dependent stacking interaction of the PBD model.

scribes the dynamics of a Hamiltonian system in the presence of thermal baths. The Langevin equation is given by

$$m \ddot{y}_n = -\frac{\partial W}{\partial y_n} - \frac{\partial V}{\partial y_n} - \Gamma_n \dot{y}_n + f(t), \quad (32)$$

where $W(y_n)$ and $V(y_n)$ are the potentials described in Eq. (1) of the main text. The DNA strand is split into three regions, the two ends, each of length l , serve as the Langevin thermal reservoirs at temperatures T_L and T_H . This means that the friction term Γ_n only operates for n within the thermal reservoirs. The fluctuating term $f(t)$ is Gaussian white noise which obeys the fluctuation-dissipation relation $\langle f(t)f(t') \rangle = 2\Gamma_n k_B T_{L(H)} \delta(t-t')$ for the low and high temperature reservoirs, respectively. In our simulations, the parameters of each Langevin thermostat have always been set to $l = 20$ and $\Gamma_n/m = 0.5 \text{ ps}^{-1}$.

The middle region of the length M is the free DNA strand, which is driven out of equilibrium by the Langevin reservoirs when $T_L \neq T_H$. The length of the middle region has been varied in the range $M = 50 - 200$ in our simulations. The parameters of the PBD model are given in the main text except for the sequence-dependent stacking interaction strength. These are adopted from Ref. 5 and compiled in Table I. The equations of motion are integrated with the fourth-order Runge-Kutta method. The local heat current is given by $J_n = -\left\langle \dot{y}_n \frac{\partial W(y_n, y_{n-1})}{\partial y_n} \right\rangle$. The simulations are performed long enough to allow the system to reach its steady state, where J_n does not depend on n , as long as n is within the “free” middle region of DNA.

* chihchun@lanl.gov

† mpzwolak@physics.oregonstate.edu

- [1] M. Peyrard and A. R. Bishop, Phys. Rev. Lett., **62**, 2755 (1989).
- [2] T. Dauxois, M. Peyrard, and A. R. Bishop, Phys. Rev. E, **47**, R44 (1993).
- [3] T. Dauxois, M. Peyrard, and A. R. Bishop, Phys. Rev. E, **47**, 684 (1993).
- [4] A. Campa and A. Giansanti, Phys. Rev. E, **58**, 3585 (1998).
- [5] B. S. Alexandrov, V. Gelev, Y. Monisova, L. B. Alexan-

- drov, A. R. Bishop, K. Ø. Rasmussen, and A. Usheva, *Nucleic Acids Res.*, **37**, 2405 (2009).
- [6] K. A. Velizhanin, C.-C. Chien, Y. Dubi, and M. Zwolak, *Phys. Rev. E*, **83**, 050906 (1 (2011)).
- [7] A. Casher and J. L. Lebowitz, *J. Math. Phys.*, **12**, 1701 (1971).
- [8] A. Dhar, *Phys. Rev. Lett.*, **86**, 5882 (1 (2001)).
- [9] Y.-L. Zhang, W.-M. Zheng, J.-X. Liu, and Y. Z. Chen, *Phys. Rev. E*, **56**, 7100 (1997).